

# 150MHz phase-locked loop

568A

## DESCRIPTION

The 568A is a monolithic phase-locked loop (PLL) which operates from 1Hz to frequencies in excess of 150MHz and features an extended supply voltage range and a lower temperature coefficient of the  $V_{CO}$  center frequency in comparison with its predecessor, the NE568. The 568A is function and pin-compatible with the 568, requiring only minor changes in peripheral circuitry (see Figure 1.). The integrated circuit consists of a limiting amplifier, a current-controlled oscillator (ICO), a phase detector, a level shift circuit, V/I and I/V converters, an output buffer, and bias circuitry with temperature and frequency compensating characteristics. The design of the 568A is particularly well-suited for demodulation of FM signals with extremely large deviation in systems which require a highly linear output. In satellite receiver applications with a 70MHz IF, the 568A will demodulate  $\pm 20\%$  deviations with less than 1.0% typical non-linearity. In addition to high linearity, the circuit has a loop filter which can be configured with series or shunt elements to optimize loop dynamic performance. The 568A is available in 20-pin dual in-line ceramic package.

## ELECTRICAL CHARACTERISTICS

The electrical characteristics listed below are actual tests (unless otherwise stated) performed on each device with an automatic IC tester prior to shipment. Performance of the device in automated test set-up is not necessarily optimum. The 568A is layout-sensitive. Evaluation of performance for correlation to the data sheet should be done with the circuit and layout of Figures 1. & 2. with the evaluation unit soldered in place. (Do not use a socket!)

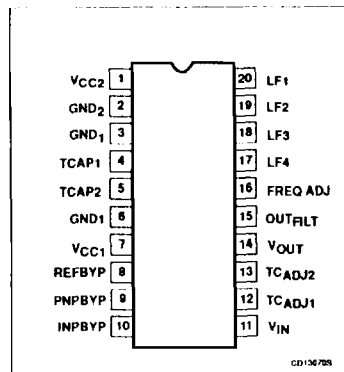
## FEATURES

- Operation to 150MHz
- High linearity buffered output
- Series or shunt loop filter component capability
- External loop gain control
- Temperature compensated
- ESD protected<sup>1</sup>

## APPLICATIONS

- Satellite receivers
- Fiber optic video links
- VHF FSK demodulators
- Clock Recovery

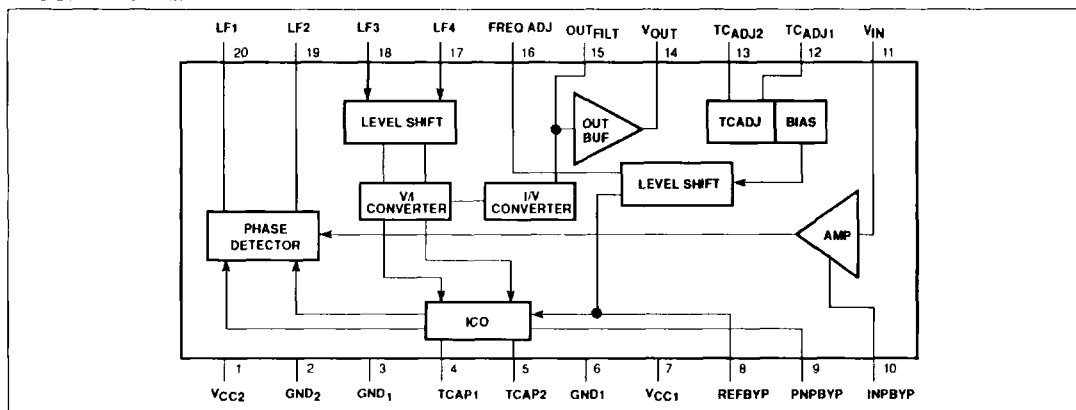
## PIN CONFIGURATION



## ORDERING INFORMATION

| DESCRIPTION        | ORDER CODE |
|--------------------|------------|
| 20-Pin Ceramic DIP | 568A/BLA   |

## BLOCK DIAGRAM



### NOTE:

1. Pins 4 and 5 can tolerate 1000V only, and all other pins, greater than 2000V for ESD (human body model).

## 150MHz phase-locked loop

568A

## ABSOLUTE MAXIMUM RATINGS

| SYMBOL            | PARAMETER                              | RATING      | UNITS |
|-------------------|----------------------------------------|-------------|-------|
| V <sub>CC</sub>   | Supply voltage                         | 6           | V     |
| T <sub>amb</sub>  | Operating free-air ambient temperature | -55 to +125 | °C    |
| T <sub>J</sub>    | Junction temperature                   | +150        | °C    |
| T <sub>STG</sub>  | Storage temperature range              | -65 to +150 | °C    |
| P <sub>DMAX</sub> | Maximum power dissipation              | 400         | mW    |
| θ <sub>JA</sub>   | Thermal resistance                     | 85          | °C/W  |

## DC ELECTRICAL CHARACTERISTICS

V<sub>CC</sub> = 5V; T<sub>amb</sub> = -55 to +125°C; f<sub>O</sub> = 70MHz, Test Circuit Figure 1., f<sub>IN</sub> = -20dBm, R<sub>4</sub> = 3.9kΩ, unless otherwise specified.

| SYMBOL          | PARAMETER      | TEST CONDITIONS | LIMITS |     |     | UNITS |
|-----------------|----------------|-----------------|--------|-----|-----|-------|
|                 |                |                 | MIN    | TYP | MAX |       |
| V <sub>CC</sub> | Supply voltage |                 | 4.5    | 5   | 5.5 | V     |
| I <sub>CC</sub> | Supply current |                 |        | 54  | 70  | mA    |

## AC ELECTRICAL CHARACTERISTICS

| SYMBOL           | PARAMETER                                           | TEST CONDITIONS                                                                                                                            | LIMITS                 |                   |             | UNITS                    |
|------------------|-----------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------|------------------------|-------------------|-------------|--------------------------|
|                  |                                                     |                                                                                                                                            | MIN                    | TYP               | MAX         |                          |
| f <sub>osc</sub> | Maximum oscillator operating frequency <sup>3</sup> |                                                                                                                                            | 150                    |                   |             | MHz                      |
|                  | Input signal level                                  |                                                                                                                                            | 50<br>-20 <sup>1</sup> |                   | 2000<br>+10 | mV <sub>p,p</sub><br>dBm |
| BW               | Demodulated bandwidth                               |                                                                                                                                            |                        | f <sub>O</sub> /7 |             | MHz                      |
|                  | Non-linearity <sup>4</sup>                          | Dev = ±20%, Input = -20dBm                                                                                                                 |                        | 1.0               | 4.0         | %                        |
|                  | Lock range <sup>2</sup>                             | Input = -20dBm                                                                                                                             | ±25                    | ±35               |             | % of f <sub>O</sub>      |
|                  | Capture range <sup>2</sup>                          | Input = -20dBm                                                                                                                             | ±20                    | ±30               |             | % of f <sub>O</sub>      |
|                  | TC of f <sub>O</sub>                                | Figure 1.                                                                                                                                  |                        | 100               |             | ppm/°C                   |
| R <sub>IN</sub>  | Input resistance                                    |                                                                                                                                            | 1                      |                   |             | kΩ                       |
|                  | Output impedance                                    |                                                                                                                                            |                        | 6                 |             | Ω                        |
|                  | Demodulated V <sub>OUT</sub>                        | Dev = ±20% of f <sub>O</sub> measured at Pin 14                                                                                            | 0.40                   | 0.52              |             | V <sub>p,p</sub>         |
|                  | AM rejection                                        | V <sub>IN</sub> = -20dBm (30% AM) referred to ±20% deviation                                                                               |                        | 50                |             | dB                       |
| f <sub>O</sub>   | Distribution <sup>5</sup>                           | Centered at 70MHz, R <sub>2</sub> = 1.2kΩ,<br>C <sub>2</sub> = 17pF, R <sub>4</sub> = 3.9Ω<br>(C <sub>2</sub> + C <sub>STRAY</sub> = 20pF) | -15                    | 0                 | +15         | %                        |
| f <sub>O</sub>   | Drift with supply                                   | 4.5V to 5.5V                                                                                                                               |                        | 2                 |             | %/V                      |

## NOTES:

- Signal level to assure all published parameters. Device will continue to function at lower levels with varying performance.
- Limits are set symmetrical to f<sub>O</sub>. Actual characteristics may have asymmetry beyond the specified limits.
- Not 100% tested, but guaranteed by design.
- Linearity is tested with incremental changes in input frequency and measurement of the DC output voltage at Pin 14 (V<sub>OUT</sub>). Non-linearity is then calculated from a straight line over the deviation range specified.
- Free-running frequency is measured as feedthrough to Pin 14 (V<sub>OUT</sub>) with no input signal applied.

# 150MHz phase-locked loop

568A

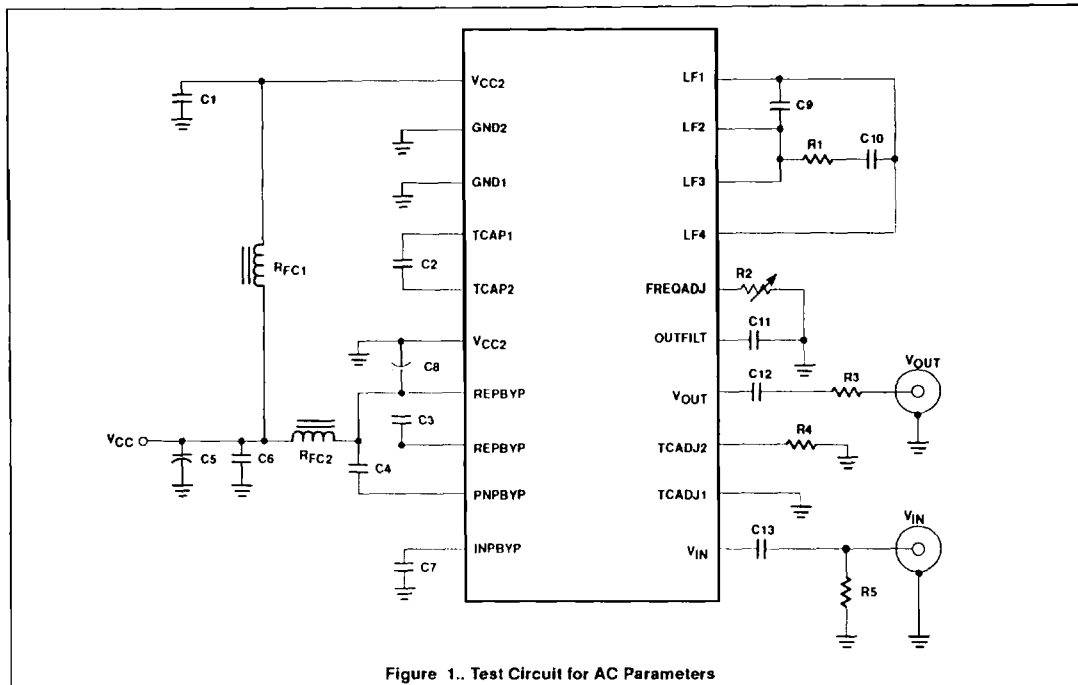


Figure 1.. Test Circuit for AC Parameters

## FUNCTIONAL DESCRIPTION

The 568A is a high-performance phase-locked loop (PLL). The circuit consists of conventional PLL elements, with special circuitry for linearized demodulated output, and high-frequency performance. The process used has NPN transistors with  $f_T > 6\text{GHz}$ . The high gain and bandwidth of these transistors make careful attention to layout and bypass critical for optimum performance. The performance of the PLL cannot be evaluated independent of the layout. The use of the application layout in this data sheet and surface-mount capacitors are high recommended as a starting point.

The input to the PLL is through a limiting amplifier with a gain of 200. The input of this amplifier is differential (Pins 10 and 11). For single-ended applications, the input must be coupled through a DC-blocking capacitor with low impedance at the frequency of interest. The single-ended input is normally applied to Pin 11 with Pin 10 AC-bypassed with a low-impedance capacitor. The input impedance is characteristically slightly above  $500\Omega$ . Impedance match is not necessary, but loading the signal source should be avoided. When the source is 50 or  $75\Omega$ , a

DC-blocking capacitor is usually all that is needed.

Input amplification is low enough to assure reasonable response time in the case of large signals, but high enough for good AM rejection. After amplification, the input signal drives one port of a multiplier-cell phase detector. The other port is driven by the current-controlled oscillator (ICO). The output of the phase comparator is a voltage proportional to the phase difference of the input and ICO signals. The error signal is filtered with a low-pass filter to provide a DC-correction voltage, and this voltage is converted to a current which is applied to the ICO, shifting the frequency in the direction which causes the input and ICO to have a  $90^\circ$  phase relationship.

The oscillator is a current-controlled multivibrator. The current control affects the charge/discharge rate of the timing capacitor. It is common for this type of oscillator to be referred to as a voltage-controlled oscillator (VCO), because the output of the phase comparator and the loop filter is a voltage. To control the frequency of an integrated ICO multivibrator, the control signal must be

conditioned by a voltage-to-current converter. In the 568A, special circuitry predistorts the control signal to make the change in frequency a linear function over a large control-voltage range.

The free-running frequency of the oscillator depend on the value of the timing capacitor connected between Pins 4 and 5. The value of the timing capacitor depends on internal resistive components and current sources. When  $R_2 = 1.2\text{k}\Omega$  and  $R_4 = 0\Omega$ , a very close approximation of the correct capacitor value is:

$$C^* = \frac{0.0014}{f_0} \text{ F}$$

where

$$C^* = C_2 + C_{\text{STRAY}}$$

The temperature-compensation resistor,  $R_4$ , affects the actual value of capacitance. This equation is normalized to 70MHz. See Figure 3. for correction factors.

The loop filter determines the dynamic characteristics of the loop. In most PLLs, the phase detector outputs are internally connected to the ICO inputs. The 568A was

## 150MHz phase-locked loop

568A

designed with filter output to input connections from Pins 20 ( $\phi$  DET) to 17 (ICO), and Pins 19 ( $\phi$  DET) to 18 (ICO) external. This allows the use of both series and shunt loop-filter elements. The loop constraints are:

$$K_D = 0.12\text{V/Radian (Phase Detector Constant)}$$

$$K_D = 4.2 \cdot 10^9 \frac{\text{Radians}}{\text{V} \cdot \text{sec}} \text{ (ICO Constant)}$$

The loop filter determines the general characteristics of the loop. Capacitors  $C_9$ ,

$C_{10}$ , and resistor  $R_1$ , control the transient output of the phase detector. Capacitor  $C_9$  suppresses 70MHz feedthrough by interaction with 100 $\Omega$  load resistors internal to the phase detector.

$$C_9 = \frac{1}{2\pi (50) (f_0)} \text{ F}$$

At 70MHz, the calculated value is 45pF. Empirical results with the test and application

board were improved when a 56pF capacitor was used.

The natural frequency for the loop filter is set by  $C_{10}$  and  $R_1$ . If the center frequency of the loop is 70MHz and the full demodulated bandwidth is desired, i.e.,  $f_{BW} = f_0/7 = 10\text{MHz}$ , and a value for  $R_1$  is chosen, the value of  $C_{10}$  can be calculated.

$$C_{10} = \frac{1}{2\pi R_1 f_{BW}} \text{ F}$$

## PARTS LIST AND LAYOUT 70MHz APPLICATION 568A

|                  |               |            |                 |      |
|------------------|---------------|------------|-----------------|------|
| $C_1$            | 100nF         | $\pm 10\%$ | Ceramic chip    | 50V  |
| $C_2^1$          | 18nF          | $\pm 2\%$  | Ceramic chip    | 50V  |
| $C_2^2$          | 16nF          | $\pm 2\%$  | Ceramic ORChip  | 0805 |
| $C_3$            | 100nF         | $\pm 10\%$ | Ceramic chip    | 50V  |
| $C_4$            | 100nF         | $\pm 10\%$ | Ceramic chip    | 50V  |
| $C_5$            | 6.8 $\mu$ F   | $\pm 10\%$ | Tantalum        | 35V  |
| $C_6$            | 100nF         | $\pm 10\%$ | Ceramic chip    | 50V  |
| $C_7$            | 100nF         | $\pm 10\%$ | Ceramic chip    | 50V  |
| $C_8$            | 100nF         | $\pm 10\%$ | Ceramic chip    | 50V  |
| $C_9$            | 47pF          | $\pm 2\%$  | Ceramic chip    | 50V  |
| $C_{10}$         | 560pF         | $\pm 2\%$  | Ceramic chip    | 50V  |
| $C_{11}$         | 47pF          | $\pm 2\%$  | Ceramic OR chip | 50V  |
| $C_{12}$         | 100nF         | $\pm 10\%$ | Ceramic OR chip | 50V  |
| $C_{13}$         | 100nF         | $\pm 10\%$ | Ceramic OR chip | 50V  |
| $R_1$            | 27 $\Omega$   | $\pm 10\%$ | Carbon          | 1/4W |
| $R_2$            | 2k $\Omega$   |            | Trim pot        |      |
| $R_3^3$          | 43 $\Omega$   | $\pm 10\%$ | Ceramic chip    | 1/4W |
| $R_4^4$          | 3.9k $\Omega$ | $\pm 10\%$ | Ceramic chip    | 1/4W |
| $R_5^3$          | 50 $\Omega$   | $\pm 10\%$ | Ceramic chip    | 1/4W |
| RFC <sub>1</sub> | 10 $\mu$ H    | $\pm 10\%$ | Surface mount   |      |
| RFC <sub>2</sub> | 10 $\mu$ H    | $\pm 10\%$ | Surface mount   |      |

## NOTES:

- 18pF with Pin 12 ground and Pin 13 flat
- $C_2 + C_{STRAY} = 16\text{pF}$  for temperature-compensated configuration with  $R_4 = 3.9\text{k}\Omega$ .
- For 50 $\Omega$  setup.  $R_1 = 62\Omega$ ,  $R_3 = 75\Omega$  for 75 $\Omega$  application.
- For test configuration  $R_4 = 0\Omega$  (GND) and  $C_2 = 18\text{pF}$ .

150MHz phase-locked loop

568A

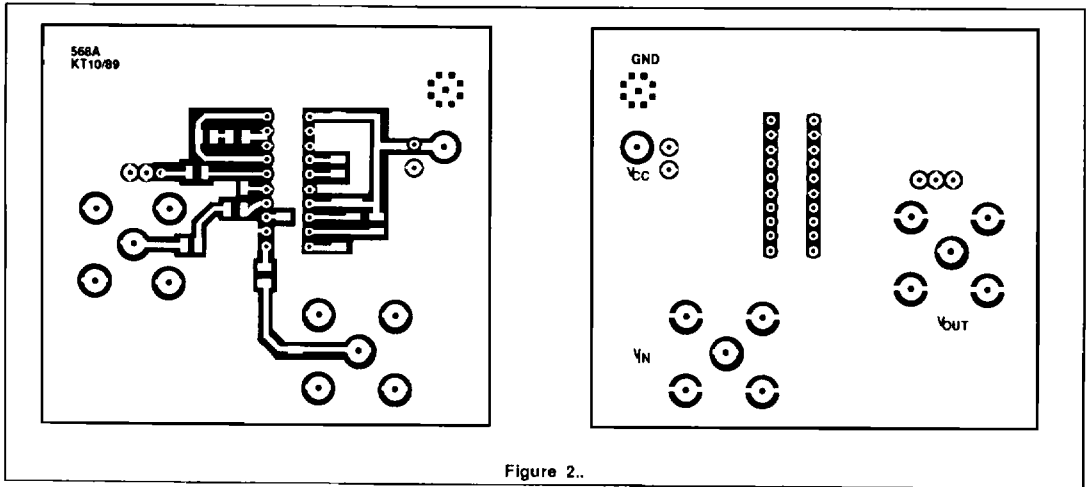


Figure 2..

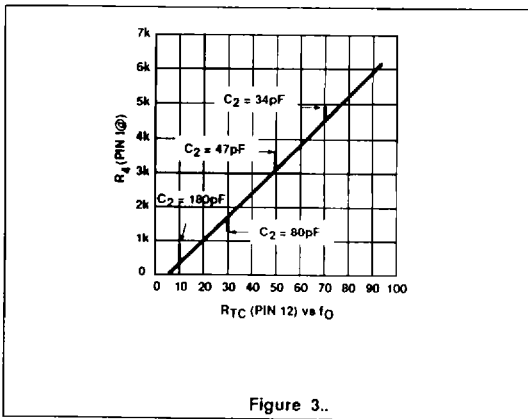
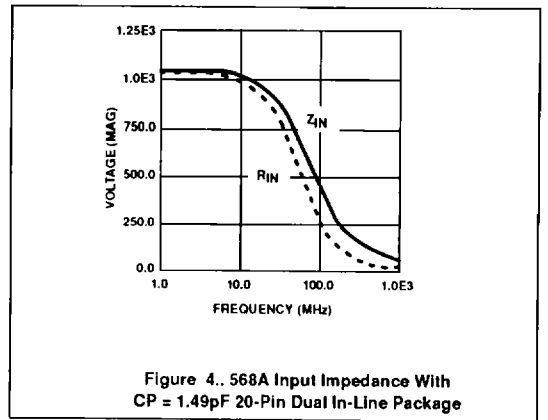


Figure 3..



150MHz phase-locked loop

568A

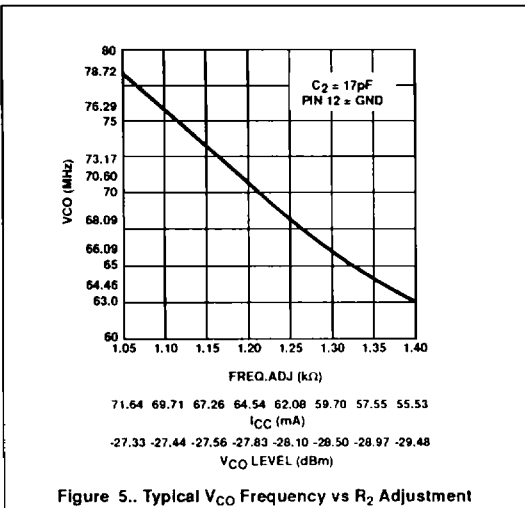


Figure 5.. Typical VCO Frequency vs R<sub>2</sub> Adjustment

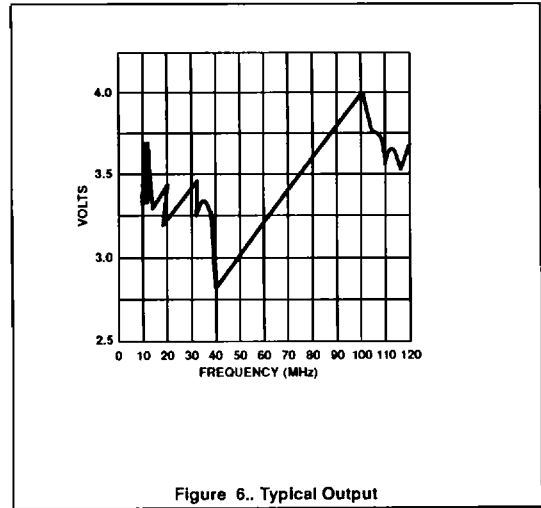


Figure 6.. Typical Output Linearity

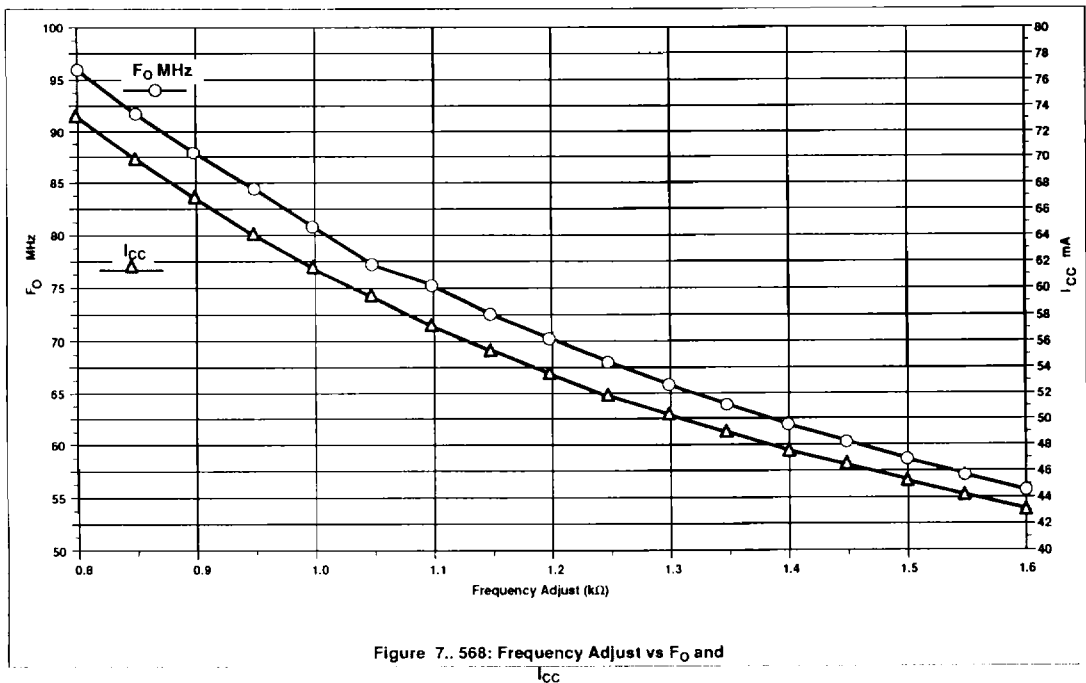


Figure 7.. 568: Frequency Adjust vs F<sub>O</sub> and ICC

# 150MHz phase-locked loop

# 568A

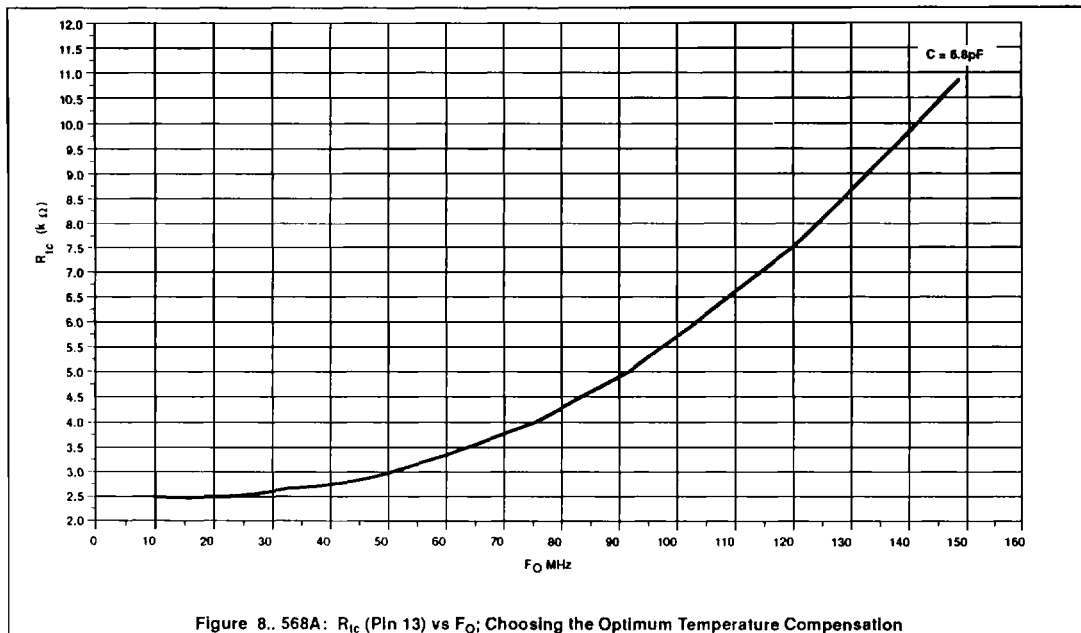


Figure 8., 568A:  $R_{1c}$  (Pin 13) vs  $F_O$ ; Choosing the Optimum Temperature Compensation Resistor